NSN 5962-01-160-7135

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches an	d 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Dissip	ation Rating:
739.0 milliwatts	
Operating Tempurature	Range:
-55.0/+125.0 degrees cels	sius
Storage Tempurature Ra	ange:
-65.0/+150.0 degrees cels	sius
End Application:	
An/fps-117 radar system	
Features Provided:	
Hermetically sealed and t	ourn in and bipolar and schottky and programmable and w/enable and w/active pull-up
Inclosure Material:	
Ceramic	
Inclosure Configuration	:
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
10 input	
Case Outline Source An	d Designator:
D-2 mil-m-38510	
Terminal Surface Treatm	nent:
Solder	
Voltage Rating And Typ	e Per Characteristic:
5.5 volts power source	
Time Rating Per Chacte	ristic:
75.00 nanoseconds prop	agation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Qua	ntity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

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